## Onsemi

### **Complementary Power Transistors**

**DPAK For Surface Mount Applications** 

## MJD31 (NPN), MJD32 (PNP)

Designed for general purpose amplifier and low speed switching applications.

#### Features

- Lead Formed for Surface Mount Applications in Plastic Sleeves
- Straight Lead Version in Plastic Sleeves ("1" Suffix)
- Lead Formed Version in 16 mm Tape and Reel ("T4" Suffix)
- Electrically Similar to Popular TIP31 and TIP32 Series
- Epoxy Meets UL 94, V-0 @ 0.125 in
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

#### **MAXIMUM RATINGS**

Symbol V <sub>CEO</sub>	Max	Unit Vdc
V <sub>CEO</sub>	10	Vde
	40 100	vuc
V <sub>CB</sub>	40 100	Vdc
$V_{\text{EB}}$	5.0	Vdc
I <sub>C</sub>	3.0	Adc
I <sub>CM</sub>	5.0	Adc
Ι <sub>Β</sub>	1.0	Adc
P <sub>D</sub>	15 0.12	W W/°C
P <sub>D</sub>	1.56 0.012	W W/°C
T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C
HBM	3B	V
MM	M3	V
	V <sub>EB</sub> I <sub>C</sub> I <sub>D</sub> P <sub>D</sub> P <sub>D</sub> T <sub>J</sub> , T <sub>stg</sub> HBM MM	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

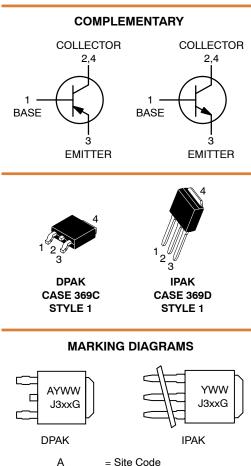
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	8.3	°C/W
Thermal Resistance, Junction-to-Ambient*	$R_{\thetaJA}$	80	°C/W
Lead Temperature for Soldering Purposes	ΤL	260	°C

\*These ratings are applicable when surface mounted on the minimum pad sizes recommended.

### SILICON **POWER TRANSISTORS** 3 AMPERES 40 AND 100 VOLTS **15 WATTS**



= Site Code

= Year = Work Week

Y

WW

хх G

= 1, 1C, 2, or 2C

= Pb-Free Package

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

#### **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Мах	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage (Note 1) ( $I_C = 30 \text{ mAdc}, I_B = 0$ ) MJD31, MJD32 MJD31C, MJD32C	V <sub>CEO(sus)</sub>	40 100		Vdc
Collector Cutoff Current (V <sub>CE</sub> = 40 Vdc, I <sub>B</sub> = 0)	 I <sub>CEO</sub>			μAdc
MJD31, MJD32 (V <sub>CE</sub> = 60 Vdc, I <sub>B</sub> = 0) MJD31C, MJD32C		_	50 50	
Collector Cutoff Current (V <sub>CE</sub> = Rated V <sub>CEO</sub> , V <sub>EB</sub> = 0)	ICES	_	20	μAdc
Emitter Cutoff Current ( $V_{BE} = 5 \text{ Vdc}, I_C = 0$ )	I <sub>EBO</sub>	_	1	mAdc
ON CHARACTERISTICS (Note 1)				
DC Current Gain ( $I_C = 1 \text{ Adc}, V_{CE} = 4 \text{ Vdc}$ ) ( $I_C = 3 \text{ Adc}, V_{CE} = 4 \text{ Vdc}$ )	h <sub>FE</sub>	25 10	_ 50	
Collector–Emitter Saturation Voltage $(I_C = 3 \text{ Adc}, I_B = 375 \text{ mAdc})$	V <sub>CE(sat)</sub>	_	1.2	Vdc

Small-Signal Current Gain h<sub>fe</sub> 20  $(I_{C} = 0.5 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f = 1 \text{ kHz})$ \_

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

V<sub>BE(on)</sub>

 $f_{\mathsf{T}}$ 

Vdc

MHz

1.8

\_

\_

3

1. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2%. 2. f<sub>T</sub> =  $|h_{fe}| \bullet f_{test}$ .

Base-Emitter On Voltage

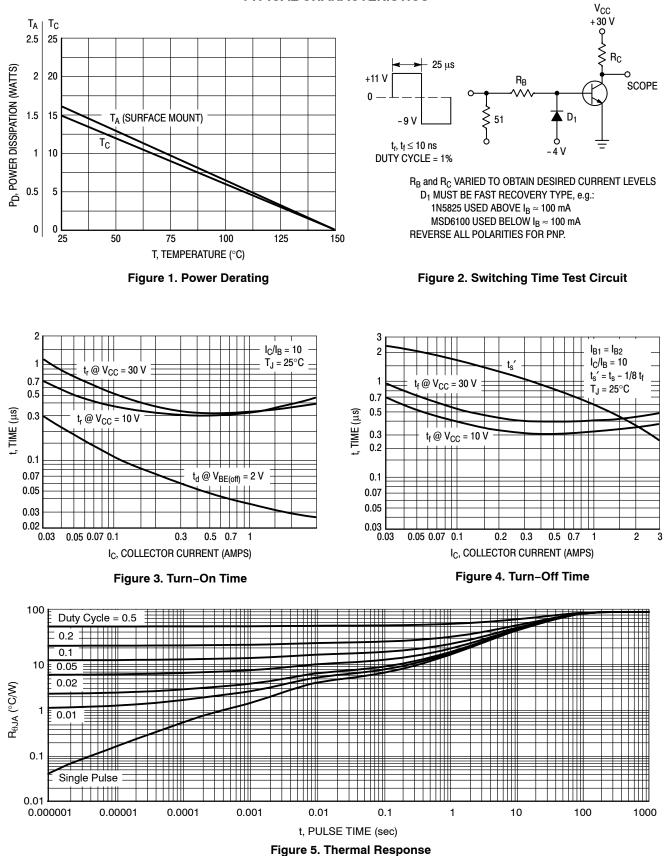
 $(I_C = 3 \text{ Adc}, V_{CE} = 4 \text{ Vdc})$ 

DYNAMIC CHARACTERISTICS

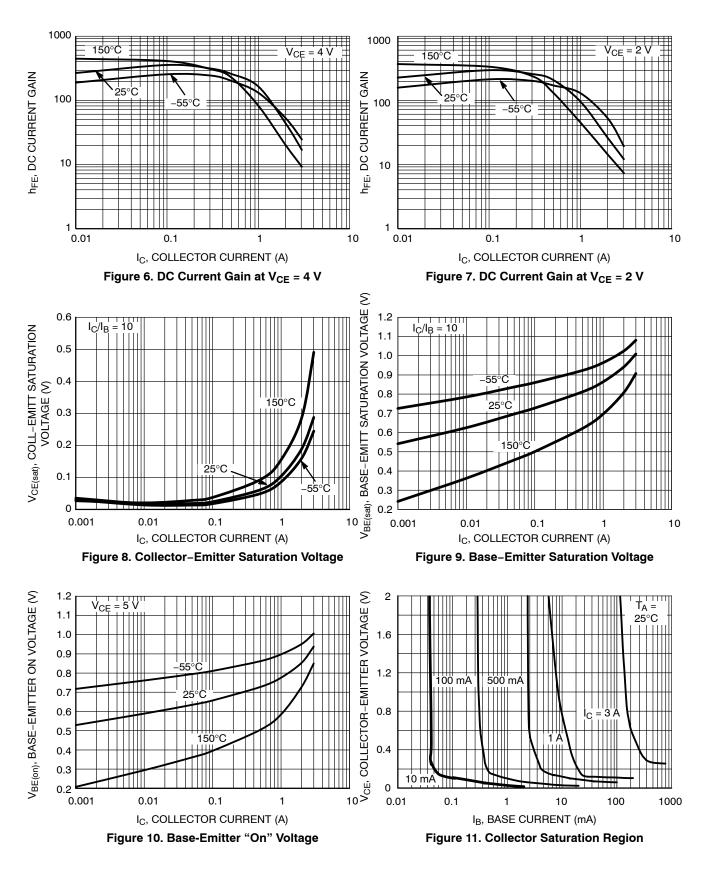
Current Gain - Bandwidth Product (Note 2)

 $(I_C = 500 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f_{test} = 1 \text{ MHz})$ 

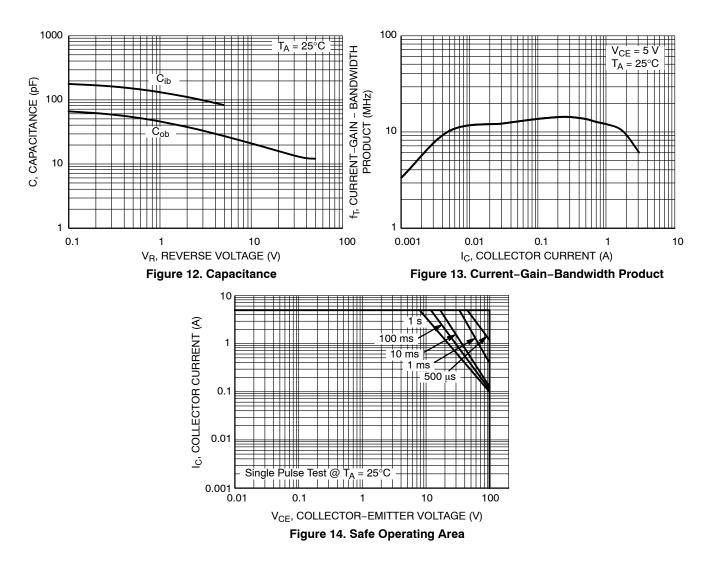
#### **TYPICAL CHARACTERISTICS**



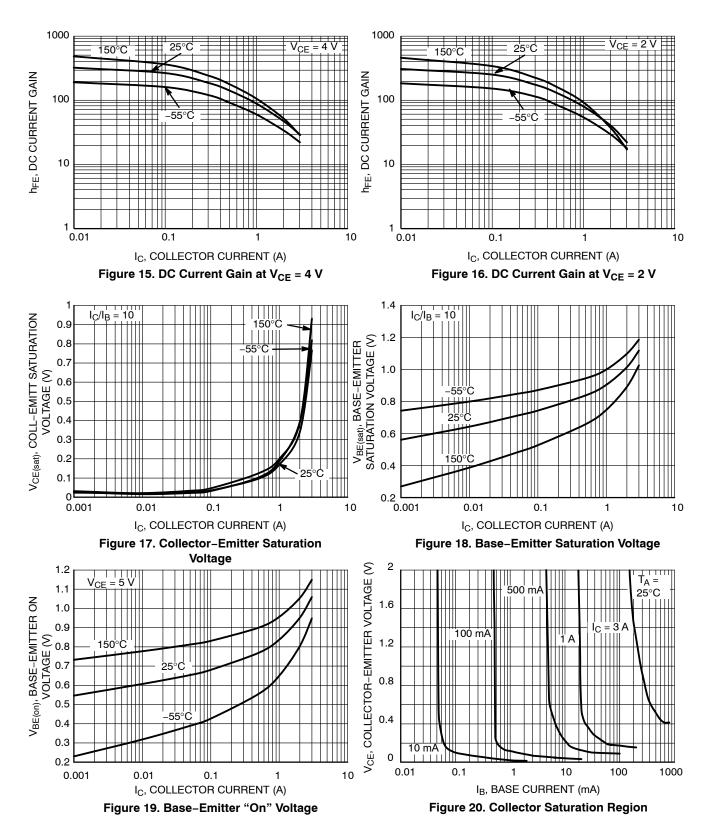
#### **TYPICAL CHARACTERISTICS – MJD31, MJD31C (NPN)**



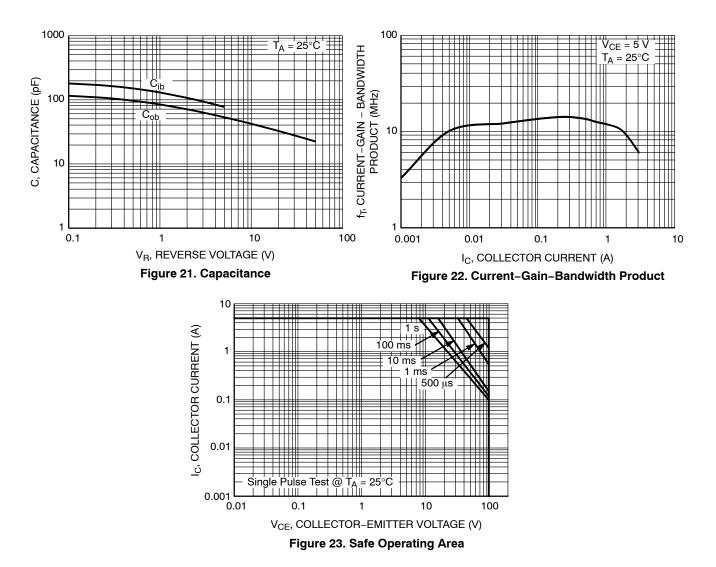
#### TYPICAL CHARACTERISTICS - MJD31, MJD31C (NPN)



#### TYPICAL CHARACTERISTICS - MJD32, MJD32C (PNP)



#### **TYPICAL CHARACTERISTICS**



#### **ORDERING INFORMATION**

Device	Package Type Package		Shipping <sup>†</sup>	
MJD31CG	DPAK (Pb-Free)	369C	75 Units / Rail	
NJVMJD31CG*	DPAK (Pb–Free)	369C	75 Units / Rail	
MJD31C1G	IPAK (Pb-Free)	369D	75 Units / Rail	
MJD31CRLG	DPAK (Pb-Free)	369C	1,800 / Tape & Reel	
NJVMJD31CRLG*	DPAK (Pb-Free)	369C	1,800 / Tape & Reel	
MJD31CT4G	DPAK (Pb-Free)	369C	2,500 / Tape & Reel	
NJVMJD31CT4G*	DPAK (Pb-Free)	369C	2,500 / Tape & Reel	
MJD31T4G	DPAK (Pb-Free)	369C	2,500 / Tape & Reel	
NJVMJD31T4G*	DPAK (Pb-Free)	369C	2,500 / Tape & Reel	
MJD32CG	DPAK (Pb-Free)	369C	75 Units / Rail	
NJVMJD32CG*	DPAK (Pb-Free)	369C	75 Units / Rail	
MJD32CRLG	DPAK (Pb-Free)	369C	1,800 / Tape & Reel	
MJD32CT4G	DPAK (Pb-Free)	369C	2,500 / Tape & Reel	
NJVMJD32CT4G*	DPAK (Pb-Free)	369C	2,500 / Tape & Reel	
MJD32RLG	DPAK (Pb-Free)	369C	1,800 / Tape & Reel	
MJD32T4G	DPAK (Pb-Free)	369C	2,500 / Tape & Reel	
NJVMJD32T4G*	DPAK (Pb-Free)	369C	2,500 / Tape & Reel	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
\*NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP

Capable.

DATE 15 DEC 2010



IPAK CASE 369D-01 **ISSUE C** С в -SCALE 1:1 v Ε R 7 4 Α S 2 3 1 -T-7 SEATING κ ۱I J F н D 3 PL G 🖛 🔶 0.13 (0.005) 🔘 T

> STYLE 3: PIN 1. ANODE

CATHODE
ANODE

4. CATHODE

COLLECTOR

STYLE 7: PIN 1. GATE 2. COLLECTOR 3. EMITTER

4.

STYLE 2: PIN 1. GATE

STYLE 6: PIN 1. MT1 2. MT2 3. GATE

4. MT2

DRAIN
SOURCE

4. DRAIN

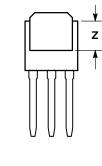
STYLE 1: PIN 1. BASE

2. COLLECTOR

EMITTER
COLLECTOR

STYLE 5: PIN 1. GATE 2. ANODE 3. CATHODE

4. ANODE



STYLE 4: PIN 1. CATHODE

ANODE
GATE

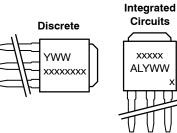
4. ANODE

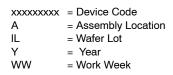
	INCHES MILLIME			IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.235	0.245	5.97	6.35	
В	0.250	0.265	6.35	6.73	
С	0.086	0.094	2.19	2.38	
D	0.027	0.035	0.69	0.88	
Е	0.018	0.023	0.46	0.58	
F	0.037	0.045	0.94	1.14	
G	0.090 BSC		2.29 BSC		
Н	0.034	0.040	0.87	1.01	
J	0.018	0.023	0.46	0.58	
к	0.350	0.380	8.89	9.65	
R	0.180	0.215	4.45	5.45	
S	0.025	0.040	0.63	1.01	
V	0.035	0.050	0.89	1.27	
Ζ	0.155		3.93		

 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: INCH.

NOTES:

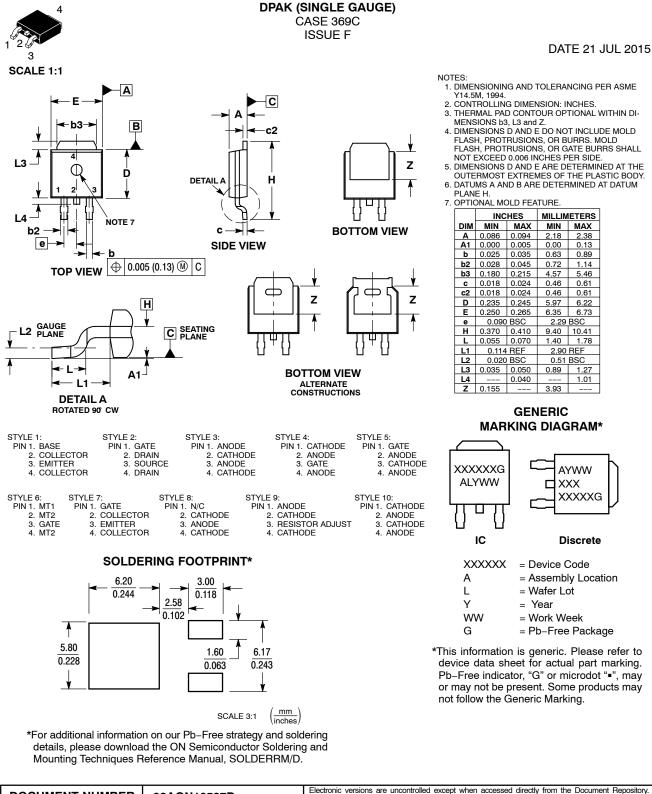
#### MARKING DIAGRAMS





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